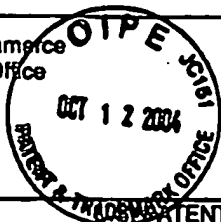


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(Rev. 8-88) Patent and Trademark Office

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Applicant: Nayfeh et al.

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Group: 1754

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Michael Medner

Date Considered

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